



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Turner et al.

Attorney Docket No.: NOVLP074

Application No.: 09/998,993

Examiner: Maldonado, Julio J.

Filed: November 15, 2001

Group: 2823

Title: Phosphorous-Doped Silicon Dioxide Process
to Customize Contact Etch Profiles

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first-class mail on June 23, 2003 in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Signed:

Latrice R. Williams

AMENDMENT A

Mail Stop Petition
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action dated September 25, 2002 ("Office Action"), please amend the above-identified patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begin on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.

07/30/2003 YSHORT 00000003 500388 09998993

01 FC:1201 168.00 DA
02 FC:1202 90.00 DA